

Vishay High Power Products

Thyristor/Diode and Thyristor/Thyristor (ADD-A-PAKTM Generation 5 Power Modules), 27 A



ADD-A-PAKTM

PRODUCT SUMMARY					
$I_{T(AV)}$ or $I_{F(AV)}$	27 A				

MECHANICAL DESCRIPTION

The Generation 5 of ADD-A-PAKTM modules combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device. The Cu baseplate allows an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improved thermal spread. The Generation 5 of AAP modules is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

FEATURES

- · High voltage
- · Industrial standard package
- · Thick copper baseplate
- UL E78996 approved
- 3500 V_{RMS} isolating voltage
- · Totally lead (Pb)-free
- · Designed and qualified for industrial level

BENEFITS

- Up to 1600 V
- Fully compatible TO-240AA
- · High surge capability
- · Easy mounting on heatsink
- Al₂0₃ DBC insulator
- · Heatsink grounded

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery chargers.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES						
I _{T(AV)} or I _{F(AV)}	85 °C	27						
I _{O(RMS)}	As AC switch	60	1 .					
I _{TSM,} I _{FSM}	50 Hz	400	A					
	60 Hz	420						
l ² t	50 Hz	50 Hz 800						
	60 Hz	730	A ² s					
I ² √t		8000	A ² √s					
V _{RRM}	Range	400 to 1600	V					
T _{Stg}		40 to 105	°C					
TJ		- 40 to 125	•0					

VSK.26..PbF Series

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I _{RRM,} I _{DRM} AT 125 °C mA			
	04	400	500	400				
	06	600	700	600				
	08	800	900	800				
VSK.26	10	1000	1100	1000	15			
	12	1200	1300	1200				
	14	1400	1500	1400				
	16	1600	1700	1600				

PARAMETER	SYMBOL		VALUES	UNITS			
Maximum average on-state current (thyristors)	I _{T(AV)}	180° conduction	180° conduction, half sine wave,				
Maximum average forward current (diodes)	I _{F(AV)}	T _C = 85 °C	T _C = 85 °C				
Maximum continuous RMS on-state current as AC switch	I _{O(RMS)}	•	or (RMS)			Α	
		t = 10 ms	No voltage		400	,,	
		t = 8.3 ms	reapplied	Sinusoidal	420		
Maximum peak, one-cycle	I _{TSM}	t = 10 ms	100 % V _{RRM}	half wave, initial $T_J = T_J$ maximum	335		
non-repetitive on-state or forward current	or	t = 8.3 ms	reapplied		350		
or forward current	I _{FSM}	t = 10 ms	T - 25 °C n	o voltage reapplied	470		
		t = 8.3 ms	1j = 25 C, 11	o voltage reapplied	490		
	l ² t	t = 10 ms	No voltage		800		
		t = 8.3 ms	reapplied	Initial $T_J = T_J \text{ maximum}$	730	A ² s	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		560		
Waximum Trior rusing		t = 8.3 ms	reapplied		510		
		t = 10 ms	T 25 °C n	o voltage reapplied	1100		
		t = 8.3 ms	1J=25 C, 110	o voltage reapplied	1000		
Maximum $I^2 \sqrt{t}$ for fusing	I ² √t ⁽¹⁾	t = 0.1 to 10 m	s, no voltage re	applied	8000	A²√s	
Maximum value or threshold voltage	V _{T(TO)} (2)	Low level (3)	T _J = T _J maximum		0.92	V	
waximum value of threshold voltage	V 1(10) \ /	High level (4)	IJ = IJ IIIaxii	num	0.95	V	
Maximum value of on-state	r _t (2)	Low level (3)	$T_J = T_J$ maximum		12.11	mΩ	
slope resistance	It \ /	High level (4)	IJ = IJ IIIaxii	iiuiii	11.82	1115.2	
Maximum peak on-state or forward voltage	V_{TM}	$I_{TM} = \pi \times I_{T(AV)}$	T _J = 25 °C	1.95	V		
Maximum peak on-state of forward voltage	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$	1.95	V			
Maximum non-repetitive rate of rise of turned on current	dI/dt	$T_J = 25$ °C, from 0.67 V_{DRM} , $I_{TM} = \pi \times I_{T(AV)}$, $I_g = 500$ mA, $t_r < 0.5$ μs , $t_p > 6$ μs			150	A/μs	
Maximum holding current	I _H	T _J = 25 °C, anode supply = 6 V, resistive load, gate open circuit			200	mA	
Maximum latching current	ΙL			V, resistive load	400		

Notes

⁽¹⁾ I^2t for time $t_x = I^2\sqrt{t} \ x \ \sqrt{t_x}$

 $^{(3)}~16.7~\%$ x π x $I_{AV} < I < \pi$ x I_{AV}

⁽²⁾ Average power = $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$

 $^{(4)}$ $I > \pi \times I_{AV}$

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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P _{GM}			10	W
Maximum average gate power	P _{G(AV)}			2.5	VV
Maximum peak gate current	I _{GM}			2.5	Α
Maximum peak negative gate voltage	- V _{GM}			10	V
		T _J = - 40 °C	Anode supply = 6 V resistive load	4.0	
Maximum gate voltage required to trigger	V_{GT}	T _J = 25 °C		2.5	
		T _J = 125 °C		1.7	
		T _J = - 40 °C	Anode supply = 6 V	270	mA
Maximum gate current required to trigger	I _{GT}	T _J = 25 °C		150	
		T _J = 125 °C	Tesistive load	80	
Maximum gate voltage that will not trigger	V_{GD}	$T_J = 125 ^{\circ}\text{C}$, rated V_I	DRM applied	0.25	V
Maximum gate current that will not trigger	I_{GD}	$T_J = 125 ^{\circ}\text{C}$, rated V_I	_{DRM} applied	6	mA

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse and off-state leakage current at V _{RRM} , V _{DRM}	I _{RRM} , I _{DRM}	T _J = 125 °C, gate open circuit	15	mA			
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted	2500 (1 min) 3500 (1 s)	V			
Maximum critical rate of rise of off-state voltage	dV/dt (1)	$T_J = 125$ °C, linear to 0.67 V_{DRM}	500	V/μs			

Note

 $^{^{(1)}}$ Available with dV/dt = 1000 V/ms, to complete code add S90 i.e. VSKT26/16AS90

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Junction operating and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C	
Maximum internal thermal resistance, junction to case per module		R _{thJC}	DC operation 0.31		14044	
Typical thermal resistance, case to heatsink	' I Buce I M		Mounting surface flat, smooth and greased	0.1	K/W	
Mauring toward 10.0/	to heatsink		A mounting compound is recommended and the torque should be rechecked after a	5	Nico	
Mounting torque ± 10 %	busbar		period of 3 hours to allow for the spread of the compound.	3	Nm	
Approximate weight				110	g	
Approximate weight				4	OZ.	
Case style			JEDEC	TO-2	240AA	

△R CONDUCTION PER JUNCTION											
DEVICES	SINE HALF WAVE CONDUCTION				RECTANGULAR WAVE CONDUCTION				UNITS		
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.26	0.23	0.27	0.34	0.48	0.73	0.17	0.28	0.36	0.49	0.73	°C/W

Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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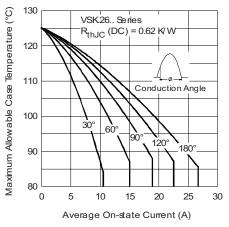


Fig. 1 - Current Ratings Characteristics

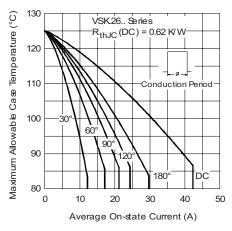


Fig. 2 - Current Ratings Characteristics

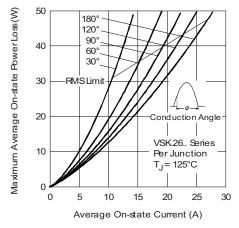


Fig. 3 - On-State Power Loss Characteristics

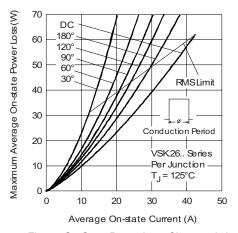


Fig. 4 - On-State Power Loss Characteristics

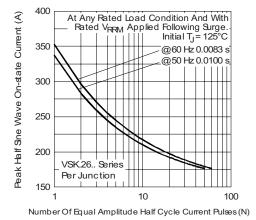


Fig. 5 - Maximum Non-Repetitive Surge Current

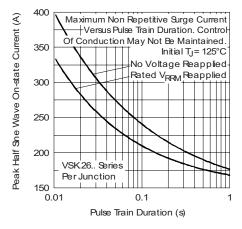


Fig. 6 - Maximum Non-Repetitive Surge Current

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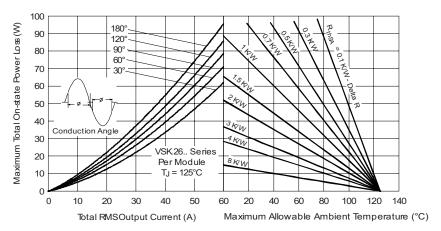


Fig. 7 - On-State Power Loss Characteristics

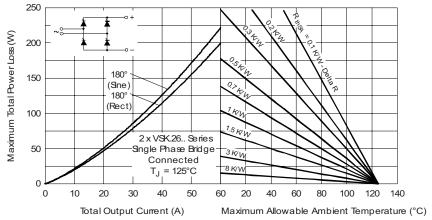


Fig. 8 - On-State Power Loss Characteristics

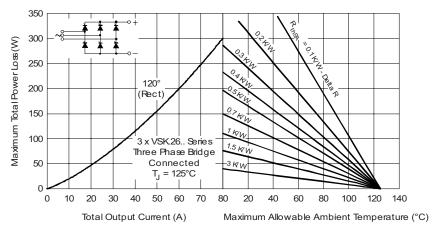


Fig. 9 - On-State Power Loss Characteristics

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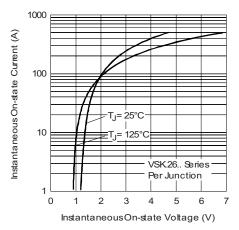


Fig. 10 - On-State Voltage Drop Characteristics

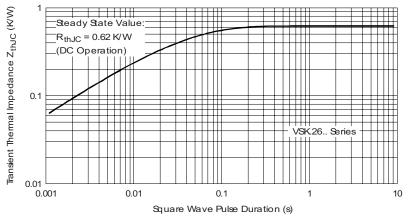


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

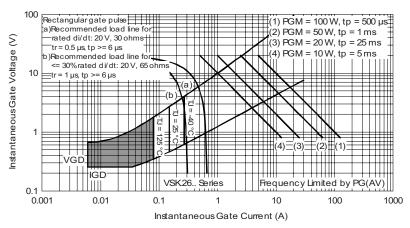


Fig. 12 - Gate Characteristics

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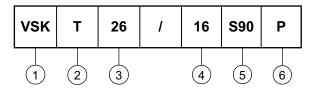
For technical questions, contact: ind-modules@vishay.com



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ORDERING INFORMATION TABLE





- 1 Module type
- 2 Circuit configuration (see end of datasheet)
- 3 Current code (1)
- 4 Voltage code (see Voltage Ratings table)
- dV/dt code: S90 = dV/dt 1000 V/µs
 No letter = dV/dt 500 V/µs
- 6 P = Lead (Pb)-free

(for details see dimensions - link at the end of datasheet)

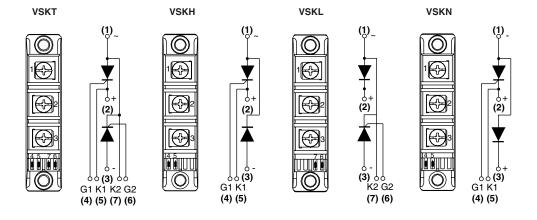
To specify change: 26 to 27

e.g.: VSKT27/16P etc.

Note

• To order the optional hardware go to www.vishay.com/doc?95172

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
Dimensions	http://www.vishay.com/doc?95085				

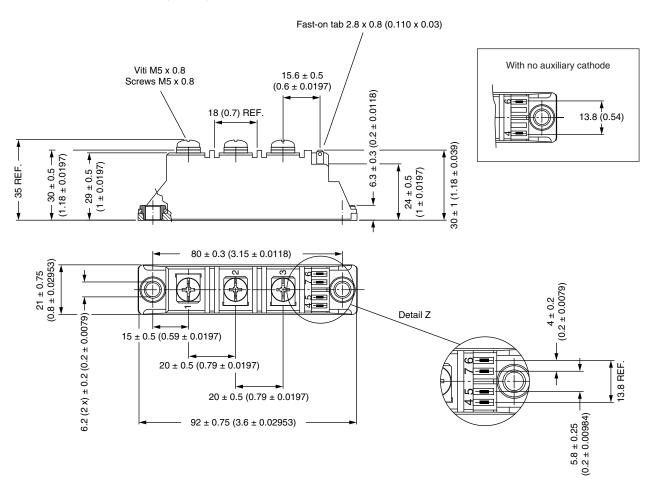
⁽¹⁾ Available with no auxiliary cathode



Vishay Semiconductors

ADD-A-PAK SCR

DIMENSIONS in millimeters (inches)



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